

### **RDS Demodulation IC**

### Overview

The LC72723 is an RDS (Radio Data System) signal demodulation IC. This IC integrates a bandpass filter, the demodulation circuit, and buffer RAM on a single chip and can read out RDS data in slave mode operation with the provision of an external clock input. It also supports master mode, in which the data is read out in synchronization with an RDS clock output provided by the IC itself.

### **Functions**

- Bandpass filter: Switched capacitor filter (SCF)
- RDS demodulation: Functions include 57kHz carrier regeneration, clock regeneration, biphase decoding, and differential decoding
- Buffer RAM: Stores 128 bits (about 100 ms) of data.
- Data output: Output can be switched between master mode and slave mode readout.
- RDS ID detection: Supports ID reset
- Standby control: Stops the crystal oscillator.
- · Fully adjustment free.

### **Ratings**

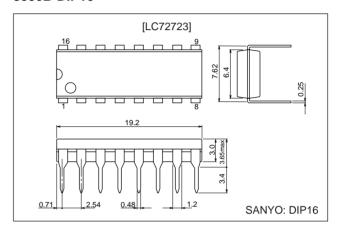
Operating supply voltage: 4.5 to 5.5 V
 Operating temperature: -40 to 85°C

• Packages: DIP16 and MFP16

### **Package Dimensions**

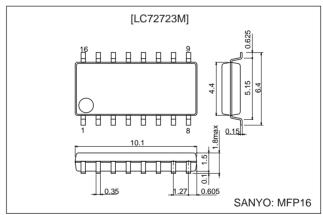
unit: mm

### 3006B-DIP16



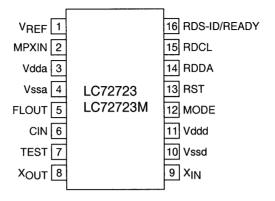
unit: mm

### 3035A-MFP16

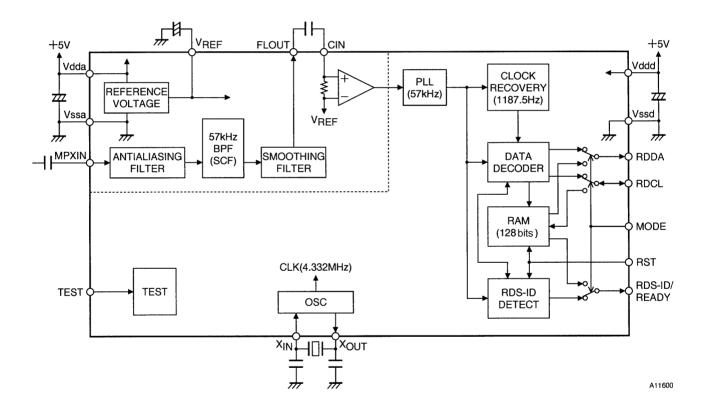


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### Pin Assignment (DIP16/MFP16)



### **Block Diagram**



### **Pin Descriptions**

Pin No.	Pin	Function	I/O	Pin circuit type		
1	VREF	Reference voltage output (Vdda/2)	Output	Vdda 1 Vssa		
2	MPXIN	Base band (multiplex) signal input	Input	↑Vdda ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓ ↓		
5	FLOUT	Subcarrier output (filter output)	Output			
6	CIN	Subcarrier input (comparator input)	Input	Vssa WREF		
3	Vdda	Analog system power supply (+5 V)	_	_		
4	Vssa	Analog system ground	_	_		
8	XOUT	Crystal element output (4.332 MHz)	Output	X <sub>IN</sub> Vddd W		
9	XIN	Crystal element input (or external reference signal input)		X <sub>OUT</sub> Vssd		
7	TEST	Test input	Input			
12	MODE	Readout mode setting (0: master, 1: slave)		Vssd		
13	RST	RDS ID and RAM reset (Active high logic)		<i>///</i> 1000		
14	RDDA	RDS data output	Output	√Vddd → Vssd		
15	RDCL	RDS clock output (master mode) RDS clock input (slave mode)	I/O	A Vddd		
16	RDS-ID/READY	RDS ID/ready output (Active low)	Output	Vssd ///		
11	Vddd	Digital system power supply (+5 V)	_	_		
10	Vssd	Digital system ground	_	_		

# $\label{eq:specifications} \textbf{Specifications} \\ \textbf{Absolute Maximum Ratings at } \mathbf{Ta} = 25^{\circ}\mathbf{C}, \mathbf{Vssd} = \mathbf{Vssa} = \mathbf{0} \ \mathbf{V}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V <sub>DD</sub> max	Vddd, Vdda *	-0.3 to 7.0	V
	V <sub>IN</sub> 1 max	TEST, MODE, RST	-0.3 to +7.0	V
Maximum input voltage	V <sub>IN</sub> 2 max	XIN, RDCL	-0.3 to Vddd + 0.3	V
	V <sub>IN</sub> 3 max	MPXIN, CIN	-0.3 to Vdda + 0.3	V
	Vo1 max	RDS-ID (READY)	-0.3 to +7.0	V
Maximum output voltage	Vo2 max	XOUT, RDDA, RDCL	-0.3 to Vddd + 0.3	V
	Vo3 max	FLOUT	-0.3 to Vdda + 0.3	V
Maximum autout aureant	lo1 max	XOUT, FLOUT, RDDA, RDCL	+3.0	mA
Maximum output current	lo2 max	RDS-ID (READY)	+20.0	mA
Allowable power discipation	Dd may	(T- < 0500)	DIP16:300	mW
Allowable power dissipation	Pd max	(Ta ≤ 85°C)	MFP16: 140	mW
Operating temperature	Topr		-40 to +85	°C
Storage temperature	Tstg		-55 to +125	°C

<sup>\*:</sup> Note that Vdda must be less than or equal to Vddd + 0.3 V

### Allowable Operating Ranges at Ta = -40 to $+85^{\circ}C$ , Vssd = Vssa = 0 V, Vddd = Vdda

Donor oton	Oh. al	Symbol Conditions		Ratings			Unit
Parameter	Symbol			min	typ	max	Onit
Supply voltage	V <sub>DD</sub>	Vddd, Vd	da: Vddd = Vdda	4.5	5.0	5.5	V
High level input valtage	V <sub>IH</sub> 1	TEST, MO	DDE, RST	07 Vddd		6.5	V
High-level input voltage	V <sub>IH</sub> 2	RDCL		0.7 Vddd		Vddd	V
Low-level input voltage	V <sub>IL</sub>	TEST, MO	DDE, RST, RDCL	0		0.3 Vddd	V
Output valtage	Vo1	RDDA, R	DCL			Vddd	V
Output voltage	Vo2	RDS-ID (READY)				6.5	V
	V <sub>IN</sub> 1	MPXIN	f = 57 ±2 KHz			50	mVrms
Input amplitude	V <sub>IN</sub> 2		100% modulation, composite	100			mVrms
	VX <sub>IN</sub>	XIN		400		1500	mVrms
Guaranteed oscillator operating range	Xtal	XIN, XOUT: C1 ≤ 120 Ω			4.332		MHz
Crystal oscillator frequency deviation	TXtal	XIN, XOUT: Fo = 4.332 MHz				±100	ppm
RDCL setup time	t <sub>CS</sub>	RDCL, RDDA		0			μs
RDCL high-level time	t <sub>CH</sub>	RDCL		0.75			μs
RDCL low-level time	t <sub>CL</sub>	RDCL		0.75			μs
Data output time	t <sub>DC</sub>	RDCL, RDDA				0.75	μS
READY output time	t <sub>RC</sub>	RDCL, READY				0.75	μs
READY low-level time	t <sub>RL</sub>	READY				107	ms

### Electrical Characteristics at Ta = -40 to $+85^{\circ}C$ , Vssd = Vssa = 0 V, Vddd = Vdda

Parameter	Cumbal	Symbol Conditions	Ratings			Unit
Parameter	Symbol		min	typ	max	Offic
Input registance	Rmpxin	MPXIN-Vssa: f = 57 KHz		23		ΚΩ
Input resistance	Rcin	CIN-Vssa: f = 57 KHz		100		ΚΩ
Internal feedback resistance	Rf	XIN		1.0		ΜΩ
Center frequency	fc	FLOUT	56.5	57.0	57.5	KHz
-3dB bandwidth	BW-3dB	FLOUT	2.5	3.0	3.5	KHz
Gain	Gain	MPXIN-FLOUT: f = 57 KHz	28	31	34	dB
	Att1	FLOUT: Δf = ±7 KHz	30			dB
Stop band attenuation	Att2	FLOUT: f < 45 KHz, f > 70 KHz	40			dB
	Att3	FLOUT: f < 20 KHz	50			dB
Reference voltage output	Vref	Vref: Vdda = 5 V		2.5		V
Hysteresis	V <sub>HIS</sub>	TEST, MODE, RST, RDCL		0.1 Vddd		V
Low-level output voltage	V <sub>OL1</sub>	RDDA, RDCL : I = 2 mA			0.4	V
Low-level output voltage	V <sub>OL2</sub>	RDS-ID (READY): I = 8 mA			0.4	V
High-level output voltage	V <sub>OH</sub>	RDDA, RDCL : I = 2 mA	Vddd - 0.4			V
High-level input current	I <sub>IH</sub> 1	TEST, MODE, RST, RDCL : V <sub>I</sub> = 6.5 V			5.0	μA
righ-level input current	I <sub>IH</sub> 2	XIN: V <sub>I</sub> = Vddd	2.0		11	μA
Low-level input current	I <sub>IL</sub> 1	TEST, MODE, RST, RDCL : V <sub>I</sub> = 0 V			5.0	μA
Low-level iliput current	I <sub>IL</sub> 2	XIN: V <sub>I</sub> = 0 V	2.0		11	μA
Output off leakage current	I <sub>OFF</sub>	RDS-ID (READY): V <sub>O</sub> = 6.5 V			5.0	μA
Current drain	ldd	Vddd + Vdda		8		mA

### **Inputs and Outputs**

TEST	MODE	Circuit operating mode	RDCL pin	RDS-ID/READY pin
0	0	Master mode	Clock output	RDS-ID output
0	1	Slave mode	Clock input	READY output
1	0	Standby mode (crystal oscillator stopped)	_	_
1	1	IC test mode (Cannot be set by users.)	_	_

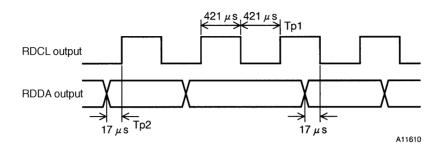
		RST pin
Ī	RST = 0	Normal operation
Ī	RST = 1	The RDS-ID and demodulation circuits are cleared, and (in slave mode) the READY state and memory are cleared.

	RDS ID/READY pin			
Master mode	de RDS-ID output (active low)			
Slave mode	Readout data ready output (active low)			

Note: The RDS-ID (READY) pin is an n-channel open-drain output, and data is read out by connecting a pull-up resistor.

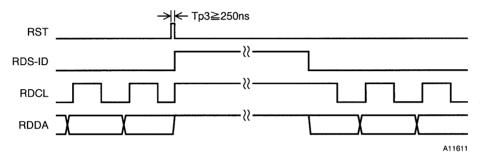
### **RDCL/RDDA Output Timing**

• Master mode



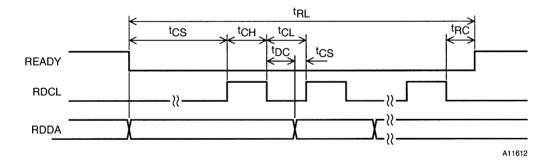
### **RST Operation**

· Master mode



Caution: After an RST input, the RDCL and RDDA outputs stop at the high level until the first RDS ID detection.

### **RDCL Control in Slave Mode**



Parameter	Cymphal	Symbol Conditions	Ratings			- Unit
Parameter	Symbol		min	typ	max	Onit
RDCL setup time	t <sub>CS</sub>	RDCL, RDDA	0			μs
RDCL high-level time	t <sub>CH</sub>	RDCL	0.75			μs
RDCL low-level time	t <sub>CL</sub>	RDCL	0.75			μs
Data output time	t <sub>DC</sub>	RDCL, RDDA			0.75	μs
READY output time	t <sub>RC</sub>	RDCL, READY			0.75	μs
Ready low-level time	t <sub>RL</sub>	READY			107	ms

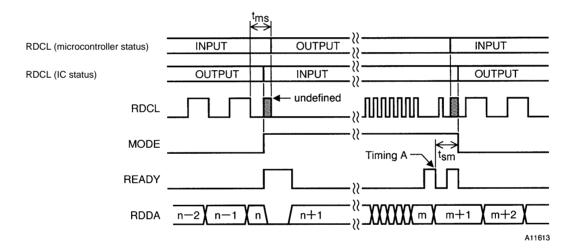
Notes:1. Start RDCL clock input after the READY signal goes low. Applications must stand by with RDCL held low when the READY pin is high.

- Each time the RDCL input is switched from low to high to low, the application must check the READY signal level after the period t<sub>RC</sub> has elapsed
  once RDCL has been set low. If READY is at the low level, the application may apply the next RDCL clock cycle. If READY is high, the application
  must stop RDCL input at that point.
- 3. When the above timing conditions are met, RDDA can be read at either the rise or fall of the RDCL signal.
- 4. After the last data from memory has been read, READY will be high once the period t<sub>RC</sub> has elapsed after the fall of the RDCL signal. If even 1 bit of data has been written to memory, READY will be low and the application will be able to read that data.

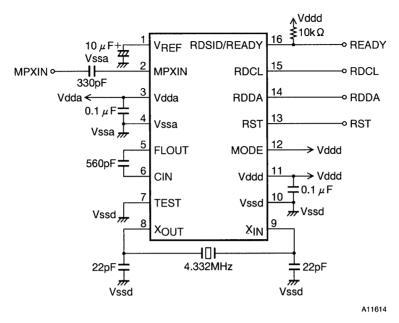
- 5. When switching channels, it is desirable to immediately reset memory and the READY pin with an RST input. If this is not done, data received on the previous channel may remain in memory. When the IC is reset, data is not written until the RDS-ID is detected, and therefore, the READY signal will go low after the RDS-ID is detected. (Although the RDS-ID is not output in slave mode, it is detected internally in the IC.) After an RST input, once an RDS-ID has been detected, all received data will be written to memory regardless of the RDS-ID detection state.
- 6. The readout mode may be switched between master and slave modes during readout. Applications must observe the following points to assure data continuity during this operation.
  - Data acquisition timing in master mode
     Data must be read on the falling edge of RDCL.
  - Timing of the switch from master mode to slave mode

    After the RDCL output goes low and the RDDA data has been acquired, the application must set MODE high immediately. Then, the microcontroller starts output by setting the RDCL signal low. The microcontroller RDCL output must start within 840 µs (tms) after RDCL went low. In this case, if the last data read in master mode was data item n, then data starting with item n+1 will be written to memory.
  - Timing of the switch from slave mode to master mode

    After all data has been read from memory and READY has gone high, the application must then wait until READY goes low once again the next time
    (timing A in the figure), immediately read out one bit of data and input the RDCL clock. Then, at the point READY goes high, the microcontroller must
    terminate RDCL output and then set MODE low. The application must switch MODE to low within 840 µs (tms) after READY goes low (timing A in the
    figure).



### LC72723 Sample Application Connection Circuit (for slave mode operation)



Caution: If the RST pin is unused, it must be connected to ground.

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